36V, Precision, Low-Power, 90μA, Single/Quad/Dual Op Amps

General Description

The MAX44244/MAX44245/MAX44248 family of parts provide ultra-precision, low-noise, zero-drift single/quad/ dual operational amplifiers featuring very low-power operation with a wide supply range. The devices incorporate a patented auto-zero circuit that constantly measures and compensates the input offset to eliminate drift over time and temperature as well as the effect of 1/f noise. These devices also feature integrated EMI filters to reduce high-frequency signal demodulation on the output. The op amps operate from either a single 2.7V to 36V supply or dual $\pm 1.35V$ to $\pm 18V$ supply. The devices are unity-gain stable with a 1MHz gain-bandwidth product and a low 90µA supply current per amplifier.

The low offset and noise specifications and high supply range make the devices ideal for sensor interfaces and transmitters.

The devices are available in μ MAX[®], SO, SOT23, and TSSOP packages and are specified over the -40°C to +125°C automotive operating temperature range.

Applications

- Sensors Interfaces
- 4mA to 20mA and 0 to10V Transmitters
- PLC Analog I/O Modules
- Weight Scales
- Portable Medical Devices

Typical Operating Circuit

Benefits and Features

- Reduces Power for Sensitive Precision Applications
 - Low 90µA Quiescent Current per Amplifier
- Eliminates the Cost of Calibration with Increased Accuracy with Maxim's Patented Autozero Circuitry
 - Very Low Input Voltage Offset 7.5µV (max)
 - Low 30nV/°C Offset Drift (max)
- Low Noise Ideal for Sensor Interfaces and Transmitters
 - $50nV/\sqrt{Hz}$ at 1kHz
 - 0.5µV_{P-P} from 0.1Hz to 10Hz
- 1MHz Gain-Bandwidth Product
 - EMI Suppression Circuitry
- Rail-to-Rail Output
- Wide Supply for High-Voltage Front Ends
 2.7V to 36V Supply Range
- µMAX, SO, SOT23, TSSOP Packages

Ordering Information appears at end of data sheet.

 μ MAX is a registered trademark of Maxim Integrated Products, Inc.

LP+ MAX6033 VREF RFF Isig R1 (4-20mA) R2 MAX5216 MAX44244 DAC R3 FLOATING GROUND RSENSE IP-



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Absolute Maximum Ratings

V _{DD} to V _{SS} 0.3V to	+40V
Common-Mode Input Voltage (V _{SS} - 0.3V) to (V _{DD} +	0.3V)
Differential Input Voltage IN_+, IN	6V
Continuous Input Current Into Any Pin±	20mA
Output Voltage to V _{SS} (OUT_) 0.3V to (V _{DD} +	0.3V)
Output Short-Circuit Duration (OUT_)	1s

Operating Temperature Range	-40°C to +125°C
Storage Temperature	-65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Thermal Characteristics (Note 1)

SO-8
Junction-to-Ambient Thermal Resistance (θ _{JA})132°C/W
Junction-to-Case Thermal Resistance (θ _{JC})
SO-14
Junction-to-Ambient Thermal Resistance (θ _{JA})120°C/W
Junction-to-Case Thermal Resistance (θ _{JC})37°C/W
SOT23
Junction-to-Ambient Thermal Resistance (θ _{JA})324.3°C/W

TSSOP

Junction-to-Ambient Thermal Resistance (θ,JA) 110°C/W
Junction-to-Case Thermal Resistance (0 _{JC})
μΜΑΧ
Junction-to-Ambient Thermal Resistance (θ _{JA})206.3°C/W
Junction-to-Case Thermal Resistance (0 _{JC})42°C/W

3°C/M

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics

 $(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k\Omega$ to $V_{DD}/2, T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $+25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	YMBOL CONDITIONS		TYP	MAX	UNITS	
POWER SUPPLY							
Supply Voltage Range	V _{DD}	Guaranteed by PSRR	2.7		36	V	
Power-Supply Rejection Ratio	PSRR	$T_A = +25^{\circ}C, V_{IN+} = V_{IN-} = V_{DD}/2 - 1V$	140	148			
(Note 3)	PSRR	-40°C < T _A < +125°C	133			dB	
Quiescent Current Per Amplifier	I _{DD}	T _A = +25°C		100	160		
(MAX4244 Only)		-40°C < T _A < +125°C			190	μA	
Quiescent Current Per Amplifier	I _{DD}	T _A = +25°C		90	130		
(MAX44245/MAX44248 Only)		-40°C < T _A < +125°C			145	μA	
DC SPECIFICATIONS							
Input Common-Mode Range	V _{CM}	Guaranteed by CMRR test	V _{SS} - 0.05		V _{DD} - 1.5	V	

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Electrical Characteristics (continued)

 $(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k\Omega$ to $V_{DD}/2, T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $+25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	CONI	DITIONS	MIN	TYP	MAX	UNITS		
Common-Mode Rejection Ratio	CMRR	T _A = +25°C, V _{CM} = V _{DD} - 1.5V	126	130		- dB			
(Note 3)	CIVIRK	-40°C < T _A < +125°0 to V _{DD} - 1.5V	C, V _{CM} = V _{SS} - 0.05V	120			dB		
Input Offect Voltage (Note 2)	N	T _A = +25°C			2	7.5	- µV		
Input Offset Voltage (Note 3)	V _{OS}	$-40^{\circ}\text{C} < \text{T}_{\text{A}} < +125^{\circ}\text{C}$	0			10	μν		
Input Offset Voltage Drift (Note 3)	TC V _{OS}				10	30	nV/°C		
Input Riss Current (Note 2)	1-	T _A = +25°C			150	300	n A		
Input Bias Current (Note 3)	I _B	$-40^{\circ}\text{C} < \text{T}_{\text{A}} < +125^{\circ}\text{C}$	0			700	- pA		
Input Offset Current (Note 3)	laa	T _A = +25°C			300	600	- pA		
Input Onset Current (Note 5)	los	-40°C < T _A < +125°C	<u> </u>			1400			
Open-Loop Gain (Note 3)	A _{VOL}	VOUT ≤ VDD - ⊢	T _A = +25°C	140	150		- dB		
			$-40^{\circ}C < T_A < +125^{\circ}C$	135					
Output Short-Circuit Current		To V _{DD} or V _{SS} , non	continuous		40		mA		
	V _{DD} -	V_{DD} - $T_A = +25^{\circ}C$				80			
	VOUT	-40°C < T _A < +125°0			110	1			
Output Voltage Swing	V _{OUT} -	$T_{A} = +25^{\circ}C$ -40°C < T _A < +125°C				50	mV		
	V _{SS}					75			
AC SPECIFICATIONS	1						1		
Input Voltage-Noise Density	e _N	f = 1kHz			50		nV/√Hz		
Input Voltage Noise		0.1Hz < f < 10Hz			500		nV _{P-P}		
Input Current-Noise Density	i _N	f = 1kHz			0.1		pA/√Hz		
Gain-Bandwidth Product	GBW				1		MHz		
Slew Rate	SR	$A_V = 1V/V, V_{OUT} = 2V_{P-P}$		$A_V = 1V/V, V_{OUT} = 2V_{P-P}$			0.7		V/µs
Capacitive Loading	CL	No sustained oscillation, $A_V = 1V/V$			400		pF		
Total Harmonic Distortion Plus Noise	THD+N	$V_{OUT} = 2V_{P-P}, A_V = +1V/V, f = 1kHz$			-100		dB		
			f = 400MHz		75		dB		
EMI Dejection Datio			f = 900MHz		78				
EMI Rejection Ratio	EMIRR	V _{RF_PEAK} = 100mV	f = 1800MHz		80				
			f = 2400MHz		90				

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Electrical Characteristics (continued)

 $(V_{DD} = 30V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k\Omega$ to $V_{DD}/2, T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $+25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	COND	DITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY							
Quiescent Current Per Amplifier		T _A = +25°C		100	160		
(MAX44244 Only)	IDD	-40°C < T _A < +125°C	2			190	μA
Quiescent Current Per Amplifier		T _A = +25°C			90	130	
(MAX44245/MAX44248 Only)	I _{DD}	-40°C < T _A < +125°C	C			145	μA
DC SPECIFICATIONS		·					
Input Common-Mode Range	V _{CM}	Guaranteed by CMR	R test	V _{SS} - 0.05		V _{DD} - 1.5	v
Common-Mode Rejection Ratio	CMPR	T _A = +25°C, V _{CM} = V V _{DD} - 1.5V	V _{SS} - 0.05V to	130	140		dD
(Note 3)	CMRR	-40°C < T_A < +125°C, V_{CM} = V_{SS} - 0.05V to V_{DD} - 1.5V 126				dB	
Input Offset Voltage (Note 3)	V _{OS}	T _A = +25°C			2	7.5	μV
input Onset Voltage (Note 5)	vos	OS -40°C < T _A < +125°C				10	μν
Input Offset Voltage Drift (Note 3)	TC V _{OS}				10	30	nV/°C
		T _A = +25°C			150	300	
Input Bias Current (Note 3)	Ι _Β	-40°C < T _A < +125°C	2			700	рА
Input Offset Current (Note 3)		T _A = +25°C			300	600	рА
input Onset Ourient (Note 0)	los	-40°C < T _A < +125°C				1400	
Open-Loop Gain (Note 3)	A _{VOL}		146	150		dB	
	, vol	≤ V _{DD} - 0.5V	-40°C < T _A < +125°C	140			
Output Short-Circuit Current		To V_{DD} or V_{SS} , none	continuous		40		mA
	V _{DD} -	T _A = +25°C				200	
	V _{OUT}	-40°C < T _A < +125°C				270	
Output Voltage Swing	V _{OUT} -	T _A = +25°C				140	mV
	V _{SS}	-40°C < T _A < +125°C				220	
AC SPECIFICATIONS							
Input Voltage-Noise Density	e _N	f = 1kHz			50		nV/√H
Input Voltage Noise		0.1Hz < f < 10Hz			500		nV _{P-P}
Input Current-Noise Density	i _N	f = 1kHz			0.1		pA/√H
Gain-Bandwidth Product	GBW				1		MHz

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Electrical Characteristics (continued)

 $(V_{DD} = 30V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k\Omega$ to $V_{DD}/2, T_A = -40^{\circ}C$ to +125°C, unless otherwise noted. Typical values are at +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Slew Rate	SR	$A_V = 1V/V, V_{OUT} = 2V_{P-P}$			0.7		V/µs	
Capacitive Loading	CL	No sustained oscillation, A _V = 1V/V			400		pF	
Total Harmonic Distortion Plus Noise	THD+N	$V_{OUT} = 2V_{P-P}, A_V = +1V/V, f = 1kHz$			-100		dB	
			f = 400MHz		75			
EMI Rejection Ratio		100.14	f = 900MHz		78			
	EMIRR	V _{RF_PEAK} = 100mV f = 1800MHz			80		- dB	
			f = 2400MHz		90			

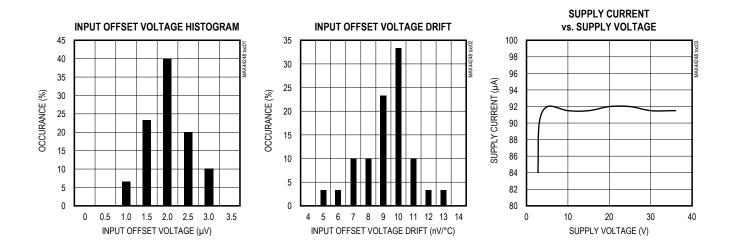
Note 2: All devices are 100% production tested at $T_A = +25$ °C. Temperature limits are guaranteed by design.

Note 3: Guaranteed by design.

Note 4: At IN+ and IN-. Defined as 20log (V_{RF PEAK}/ ΔV_{OS}).

Typical Operating Characteristics

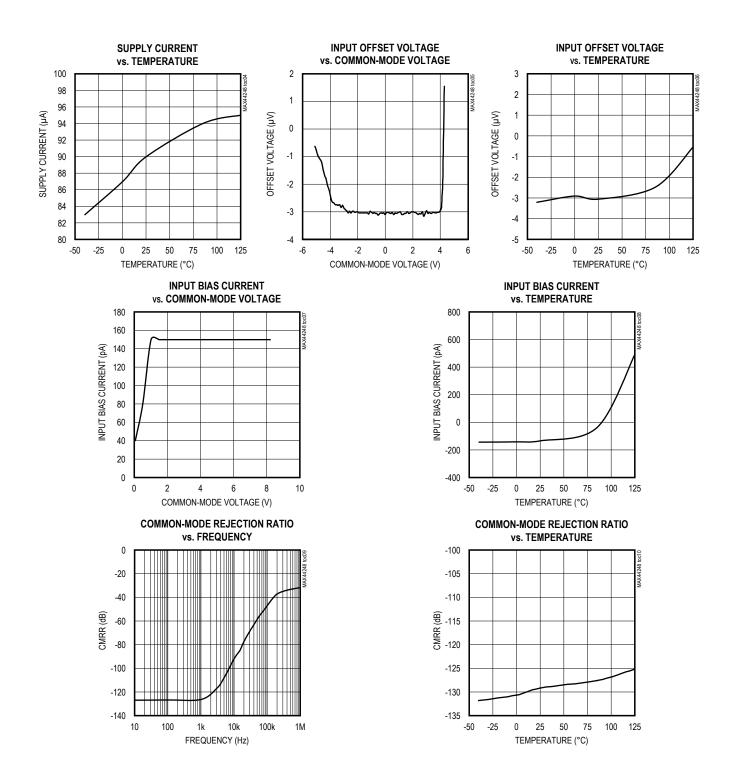
(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k Ω to V_{DD}/2. Typical values are at T_A = +25°C.)



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Typical Operating Characteristics (continued)

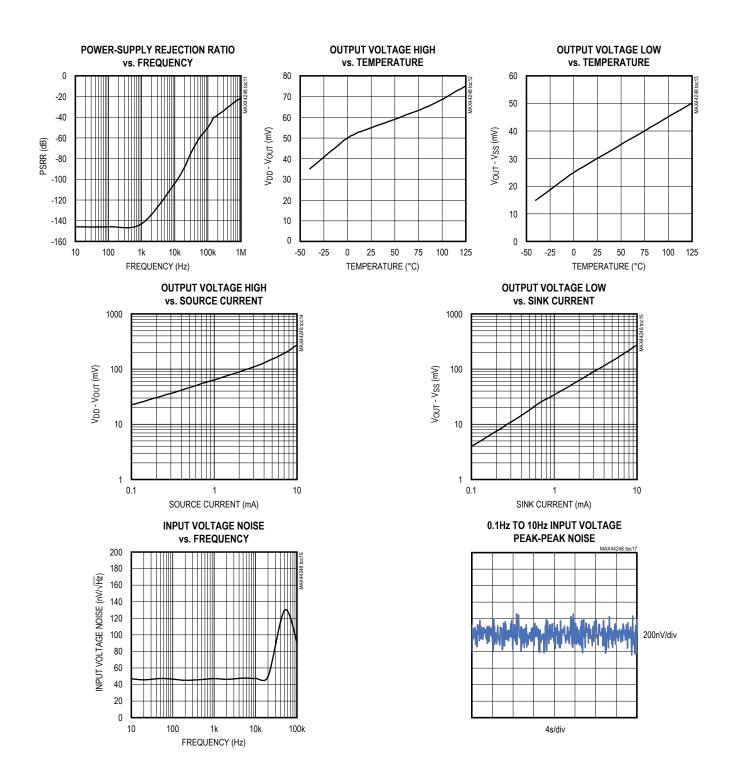
(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k Ω to V_{DD}/2. Typical values are at T_A = +25°C.)



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Typical Operating Characteristics (continued)

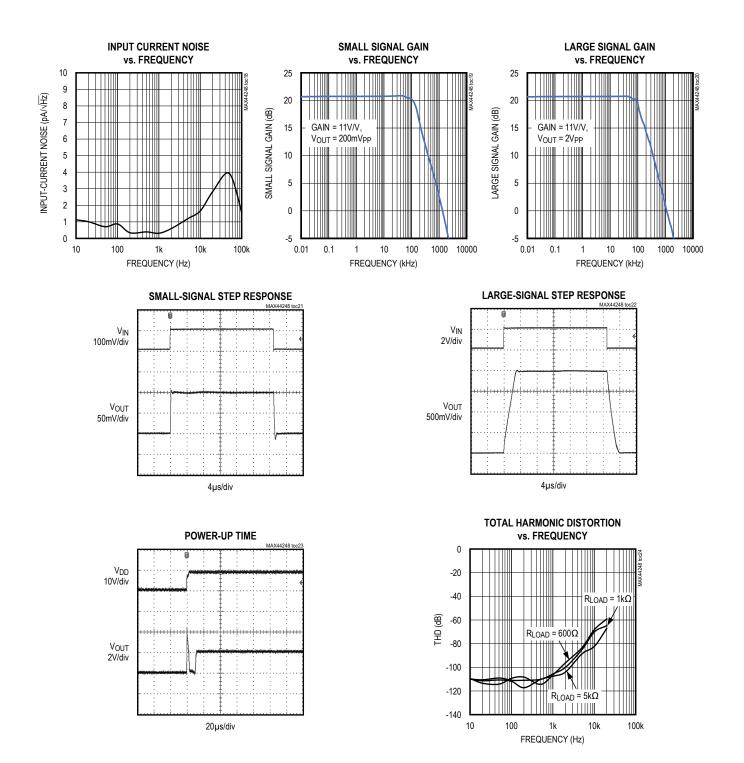
(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k Ω to V_{DD}/2. Typical values are at T_A = +25°C.)



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Typical Operating Characteristics (continued)

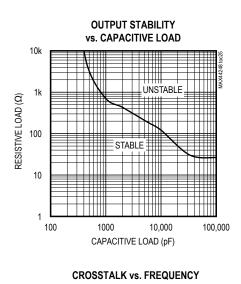
(V_DD = 10V, V_SS = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, RL = 5k Ω to V_{DD}/2. Typical values are at T_A = +25°C.)

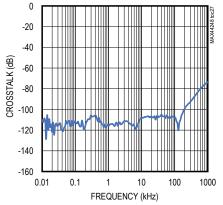


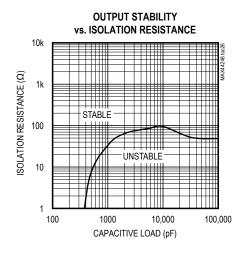
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Typical Operating Characteristics (continued)

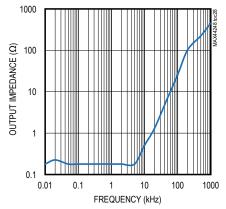
(V_{DD} = 10V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 5k Ω to V_{DD}/2. Typical values are at T_A = +25°C.)



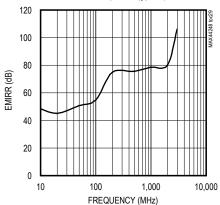




OUTPUT IMPEDANCE vs. FREQUENCY

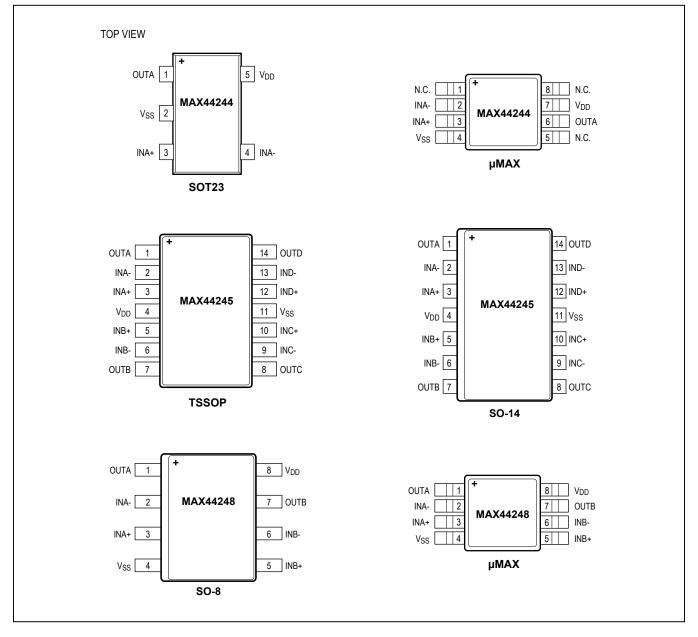


EMIRR vs. FREQUENCY



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Pin Configurations



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Pin Description

		PII	N				
MAX	44244	MAX4	4245	MAX	(44248	NAME	FUNCTION
SOT23	μΜΑΧ	SO-14	TSSOP	SO-8	μΜΑΧ]	
1	6	1	1	1	1	OUTA	Channel A Output
2	4	11	11	4	4	V _{SS}	Negative Supply Voltage
3	3	3	3	3	3	INA+	Channel A Positive Input
4	2	2	2	2	2	INA-	Channel A Negative Input
5	7	4	4	8	8	V _{DD}	Positive Supply Voltage
_	_	5	5	5	5	INB+	Channel B Positive Input
_	_	6	6	6	6	INB-	Channel B Negative Input
_	—	7	7	7	7	OUTB	Channel B Output
_	—	8	8	_	_	OUTC	Channel C Output
_	_	9	9	_	_	INC-	Channel C Negative Input
	_	10	10	_	_	INC+	Channel C Positive Input
	—	12	12	_	_	IND+	Channel D Positive Input
_	_	13	13	_	_	IND-	Channel D Negative Input
_	—	14	14	_	_	OUTD	Channel D Output
_	1, 5, 8	_	_	_	_	N.C.	No Connection. Not internally connected.

Detailed Description

The MAX44244/MAX44245/MAX44248 are highprecision amplifiers with less than $2\mu V$ (typ) input-referred offset and low input voltage-noise density at 10Hz. 1/f noise, in fact, is eliminated to improve the performance in low-frequency applications. These characteristics are achieved through an auto-zeroing technique that cancels the input offset voltage and 1/f noise of the amplifier.

External Noise Suppression in EMI Form

These devices have input EMI filters to prevent effects of radio frequency interference on the output. The EMI filters comprise passive devices that present significant higher impedance to higher frequency signals. See the EMIRR vs. Frequency graph in the <u>Typical Operating</u> Characteristics section for details.

High Supply Voltage Range

The devices feature 90μ A current consumption per channel and a voltage supply range from either 2.7V to 36V single supply or ± 1.35 V to ± 18 V split supply.

Applications Information

The devices feature ultra-high precision operational amplifiers with a high supply voltage range designed for load cell, medical instrumentation, and precision instrument applications.

4–20mA Current-Loop Communication

Industrial environments typically have a large amount of broadcast electromagnetic interference (EMI) from highvoltage transients and switching motors. This combined with long cables for sensor communication leads to high-voltage noise on communication lines. Current-Loop communication is resistant to this noise because the EMI induced current is low. This configuration also allows for low-power sensor applications to be powered from the communication lines.

The *Typical Operating Circuit* shows how the device can be used to make a current loop driver.

The circuit uses low-power components such as the MAX44244 op amp, the 16-bit MAX5216 DAC, and the high-precision 60µA-only MAX6033 reference. In this circuit, both the DAC and the reference are referred to the local ground. The MAX44244 op-amp inputs are capable of swinging to the negative supply (which is the local ground in this case). R3 acts as a current mirror with RSENSE. Therefore, if RSENSE = 50 Ω (i.e. 20mA will drop 1V) and if the current through R3 is 10µA when I_{OUT} is 20mA (0.05% error) then R3 = 100k Ω . R1 is chosen along with the reference voltage to provide the 4mA offset. R2 = 512k Ω for 20mA full scale or R2 = 614k Ω for 20% overrange. RSENSE is ratiometric with R3, R1 independently sets the offset current and R2 independently sets the DAC scaling.

Driving High-Performance ADCs

The MAX44244/MAX44245/MAX44248's low input offset voltage and low noise make these amplifiers ideal for ADC buffering. Weight scale applications require a low-noise, precision amplifier in front of an ADC. Figure 1 details an example of a load cell and amplifier driven from the same 5V supply, along with a 16-bit delta sigma ADC such as the MAX11205.

The MAX11205 is an ultra-low-power (< 300μ A, max active current), high-resolution, serial output ADC. It provides the highest resolution per unit power in the industry and is optimized for applications that require very

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high dynamic range with low power such as sensors on a 4–20mA industrial control loop. The devices provide a high-accuracy internal oscillator that requires no external components.

Layout Guidelines

The MAX44244/MAX44245/MAX44248 feature ultra-low input offset voltage and noise. Therefore, to get optimum performance follow the layout guidelines.

Avoid temperature tradients at the junction of two dissimilar metals. The most common dissimilar metals used on a PCB are solder-to-component lead and solder-to-board trace. Dissimilar metals create a local thermocouple. A variation in temperature across the board can cause an additional offset due to Seebeck effect at the solder junctions. To minimize the Seebeck effect, place the amplifier away from potential heat sources on the board, if possible. Orient the resistors such that both the ends are heated equally. It is a good practice to match the input signal path to ensure that the type and number of thermoelectric juntions remain the same. For example, consider using dummy 0Ω resistors oriented in such a way that the thermoelectric source, due to the real resistors in the signal path, are cancelled. It is recommended to flood the PCB with ground plane. The ground plane ensures that heat is distributed uniformly reducing the potential offset voltage degradation due to Seebeck effect.

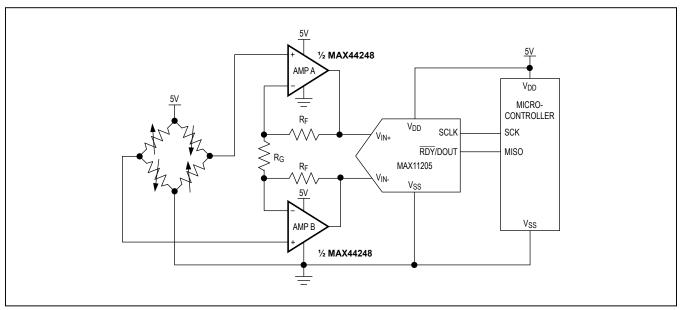


Figure 1. Weight Application

Chip Information

PROCESS: BiCMOS

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX44244AUK+	-40°C to +125°C	5 SOT23	AFMR
MAX44244AUA+	-40°C to +125°C	8 µMAX	—
MAX44245ASD+	-40°C to +125°C	14 SO	—
MAX44245AUD+	-40°C to +125°C	14 TSSOP	—
MAX44248AUA+	-40°C to +125°C	8 µMAX	_
MAX44248ASA+	-40°C to +125°C	8 SO	—

+Denotes a lead(Pb)-free/RoHS-compliant package.

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Package Information

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
5 SOT23	U5+1	21-0057	<u>90-0174</u>
8 SO	S8+4	21-0041	90-0096
8 µMAX	U8+1	21-0036	90-0092
14 SO	S14M+4	<u>21-0041</u>	<u>90-0112</u>
14 TSSOP	U14M+1	<u>21-0066</u>	<u>90-0113</u>

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	7/12	Initial release	—
1	6/13	Added the MAX44244/MAX44245 to data sheet. Updated the <i>Electrical Characteristics, Absolute Maximum Ratings, Pin Description,</i> and <i>Pin Configurations</i> .	1–13
2	9/13	Released the MAX44244 for introduction. Revised the <i>Electrical Characteristics</i>	2–5, 13
3	6/14	Corrected Figure 1 and Package Information	12, 13
4	12/14	Updated Benefits and Features section	1
5	9/15	Updated Typical Operating Circuit	1
6	11/18	Updated Typical Operating Chracteristics	7–9

For pricing, delivery, and ordering information, please visit Maxim Integrated's online storefront at https://www.maximintegrated.com/en/storefront/storefront.html.

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